

Features

- Complementary Pair: NPN(3904), PNP(3906)
- Ideal for Low Power Amplification and Switching
- Epitaxial Planar Die Construction
- Halogen Free. "Green" Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings @ 25°C Unless Otherwise Specified

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C

NPN Transistor

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6	V
Continuous Collector Current	I_C	200	mA
Power Dissipation	P_D	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	°C/W

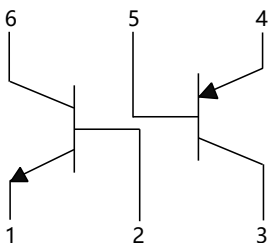
PNP Transistor

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Continuous Collector Current	I_C	-200	mA
Power Dissipation	P_D	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	°C/W

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

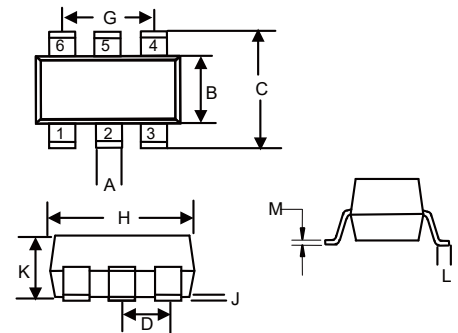
Marking: K46

Internal Structure



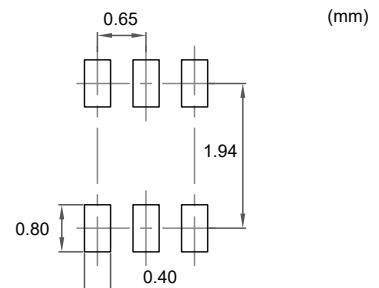
**NPN/PNP
Small Signal Surface
Mount Transistors**

SOT-363



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.006	0.014	0.15	0.35	
B	0.045	0.053	1.15	1.35	
C	0.079	0.096	2.00	2.45	
D	0.026		0.65		TYP.
G	0.047	0.055	1.20	1.40	
H	0.071	0.087	1.80	2.20	
J	----	0.004	----	0.10	
K	0.031	0.043	0.80	1.10	
L	0.010	0.018	0.26	0.46	
M	0.003	0.006	0.08	0.15	

Suggested Solder Pad Layout



Electrical Characteristics @ $T_A=25^\circ\text{C}$ Unless Otherwise Specified
NPN Transistor

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60			V	$I_C=10\mu\text{A}, I_E=0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	40			V	$I_C=1\text{mA}, I_B=0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6			V	$I_E=10\mu\text{A}, I_C=0$
Collector Cutoff Current	I_{CBO}			50	nA	$V_{CB}=30\text{V}, I_E=0$
Collector Cutoff Current	I_{CEO}			500	nA	$V_{CE}=30\text{V}, I_B=0$
Emitter Cutoff Current	I_{EBO}			50	nA	$V_{EB}=5\text{V}, I_C=0$
DC Current Gain	$h_{FE(1)}$	40				$V_{CE}=1\text{V}, I_C=0.1\text{mA}$
	$h_{FE(2)}$	70				$V_{CE}=1\text{V}, I_C=1\text{mA}$
	$h_{FE(3)}$	100		300		$V_{CE}=1\text{V}, I_C=10\text{mA}$
	$h_{FE(4)}$	60				$V_{CE}=1\text{V}, I_C=50\text{mA}$
	$h_{FE(5)}$	30				$V_{CE}=1\text{V}, I_C=100\text{mA}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			0.2	V	$I_C=10\text{mA}, I_B=1\text{mA}$
				0.3	V	$I_C=50\text{mA}, I_B=5\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	0.65		0.85	V	$I_C=10\text{mA}, I_B=1\text{mA}$
				0.95	V	$I_C=50\text{mA}, I_B=5\text{mA}$
Transition Frequency	f_T	300			MHz	$V_{CE}=20\text{V}, I_C=20\text{mA}, f=100\text{MHz}$
Delay Time	t_d			35	ns	$V_{CC}=3\text{V}, I_C=10\text{mA}, V_{BE}=0.5\text{V}, I_{B1}=1\text{mA}$
Rise Time	t_r			35	ns	
Storage Time	t_s			200	ns	$V_{CC}=3\text{V}, I_C=10\text{mA}, I_{B1}=I_{B2}=1\text{mA}$
Fall Time	t_f			50	ns	
Output Capacitance	C_{ob}			4	pF	$V_{CB}=5\text{V}, I_E=0, f=1\text{MHz}$
Noise Figure	N_F			5	dB	$V_{CE}=5\text{V}, I_C=0.1\text{mA}, f=1\text{KHz}, R_s=1\text{K}\Omega$

Electrical Characteristics @ $T_A=25^\circ\text{C}$ Unless Otherwise Specified
PNP Transistor

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40			V	$I_C=-10\mu\text{A}, I_E=0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-40			V	$I_C=-1\text{mA}, I_B=0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5			V	$I_E=-10\mu\text{A}, I_C=0$
Collector Cutoff Current	I_{CBO}			-50	nA	$V_{CB}=-30\text{V}, I_E=0$
Emitter Cutoff Current	I_{EBO}			-50	nA	$V_{EB}=-5\text{V}, I_C=0$
DC Current Gain	$h_{FE(1)}$	40				$V_{CE}=-1\text{V}, I_C=-0.1\text{mA}$
	$h_{FE(2)}$	70				$V_{CE}=-1\text{V}, I_C=-1\text{mA}$
	$h_{FE(3)}$	100		300		$V_{CE}=-1\text{V}, I_C=-10\text{mA}$
	$h_{FE(4)}$	60				$V_{CE}=-1\text{V}, I_C=-50\text{mA}$
	$h_{FE(5)}$	30				$V_{CE}=-1\text{V}, I_C=-100\text{mA}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			-0.25	V	$I_C=-10\text{mA}, I_B=-1\text{mA}$
				-0.4	V	$I_C=-50\text{mA}, I_B=-5\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	-0.65		-0.85	V	$I_C=-10\text{mA}, I_B=-1\text{mA}$
				-0.95	V	$I_C=-50\text{mA}, I_B=-5\text{mA}$
Transition Frequency	f_T	250			MHz	$V_{CE}=-20\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$
Delay Time	t_d			35	ns	$V_{CC}=-3\text{V}, I_C=-10\text{mA}, V_{BE}=-0.5\text{V}, I_{B1}=-I_{B2}=-1\text{mA}$
Rise Time	t_r			35	ns	
Storage Time	t_s			225	ns	$V_{CC}=-3\text{V}, I_C=-10\text{mA}, I_{B1}=-I_{B2}=-1\text{mA}$
Fall Time	t_f			75	ns	
Output Capacitance	C_{ob}			4.5	pF	$V_{CB}=-5\text{V}, I_E=0, f=1\text{MHz}$
Noise Figure	N_F			4	dB	$V_{CE}=-5\text{V}, I_C=-0.1\text{mA}, f=1\text{KHz}, R_s=1\text{K}\Omega$

Curve Characteristics(NPN)

Fig. 1 - Static Characteristics

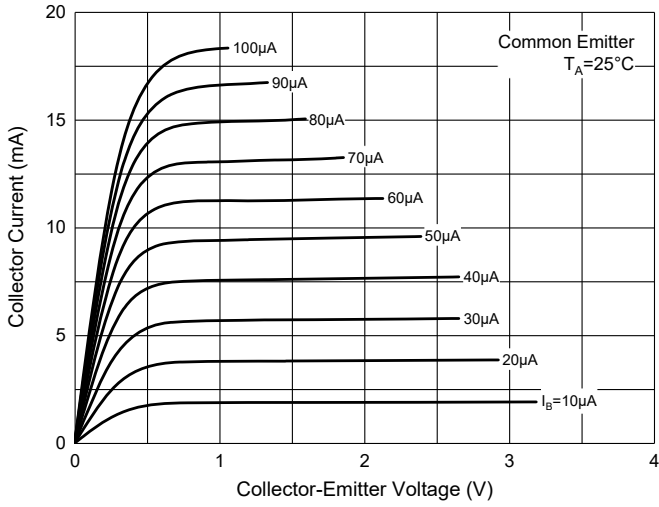


Fig. 2 - DC Current Gain Characteristics

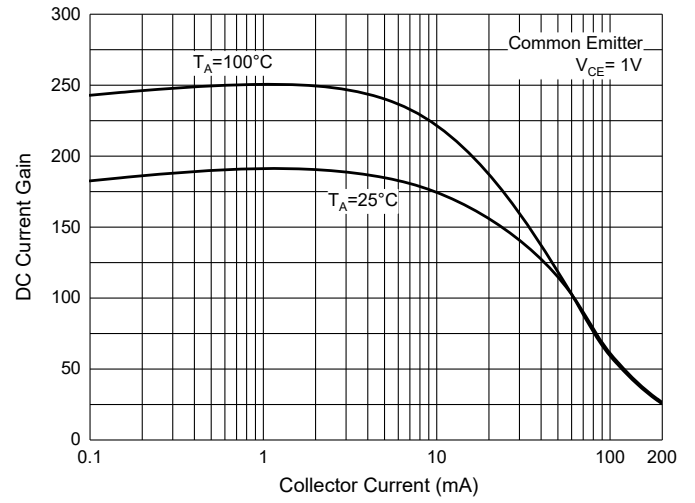


Fig. 3 - Collector-Emitter Saturation Voltage Characteristics

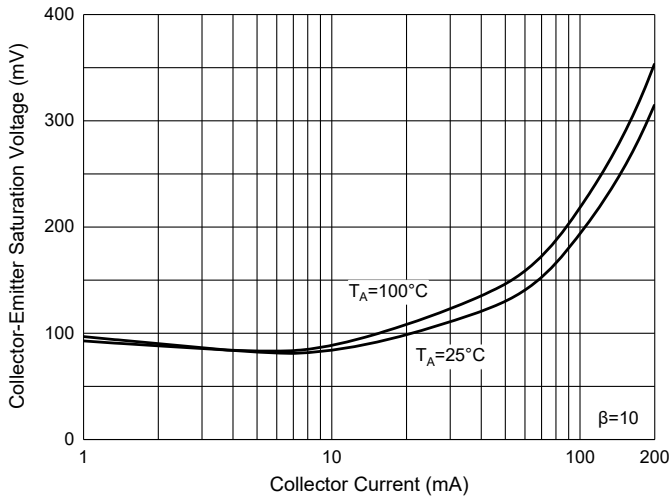


Fig. 4 - Base-Emitter Saturation Voltage Characteristics

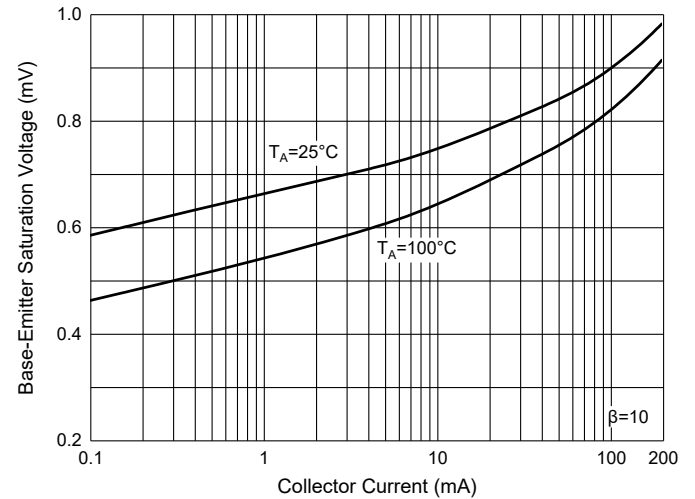


Fig. 5 - Base-Emitter Voltage Characteristics

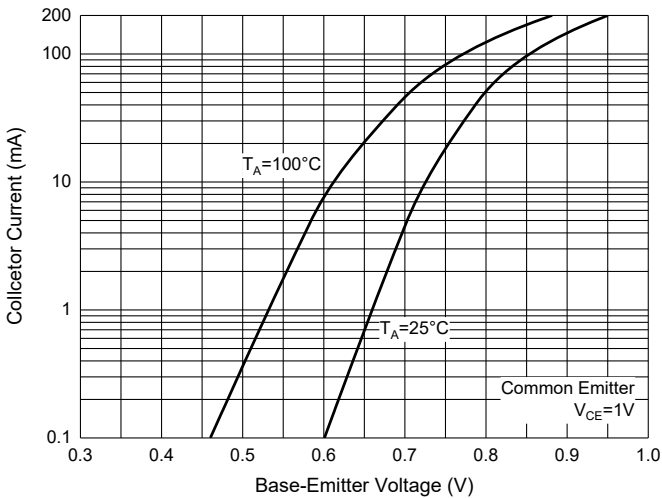
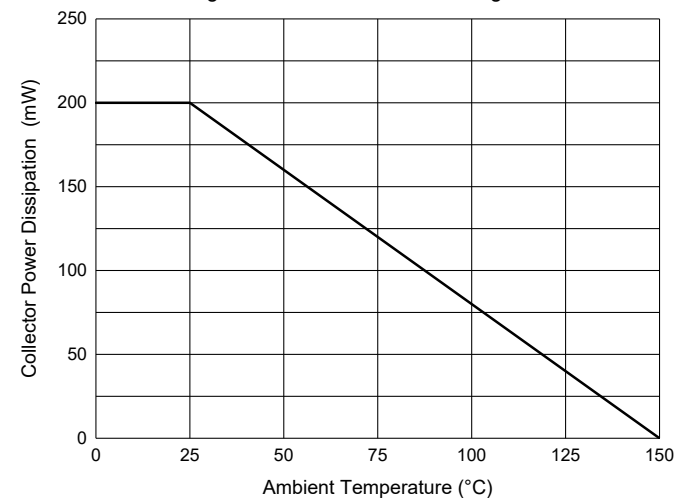


Fig. 6 - Collector Power Derating Curve



Curve Characteristics(PNP)

Fig. 7 - Static Characteristics

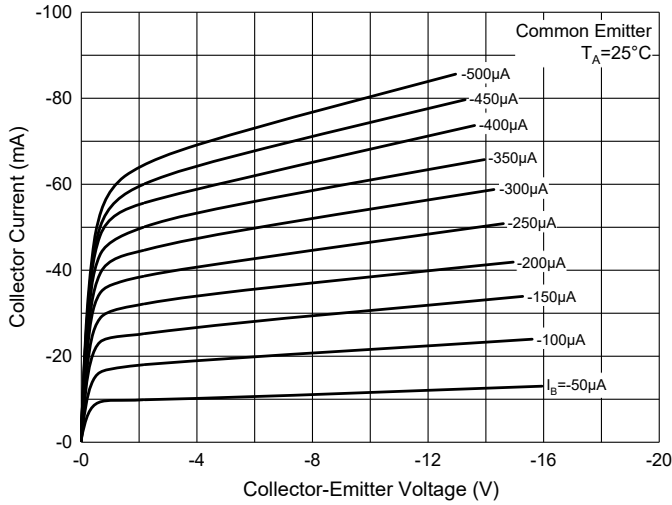


Fig. 8 - DC Current Gain Characteristics

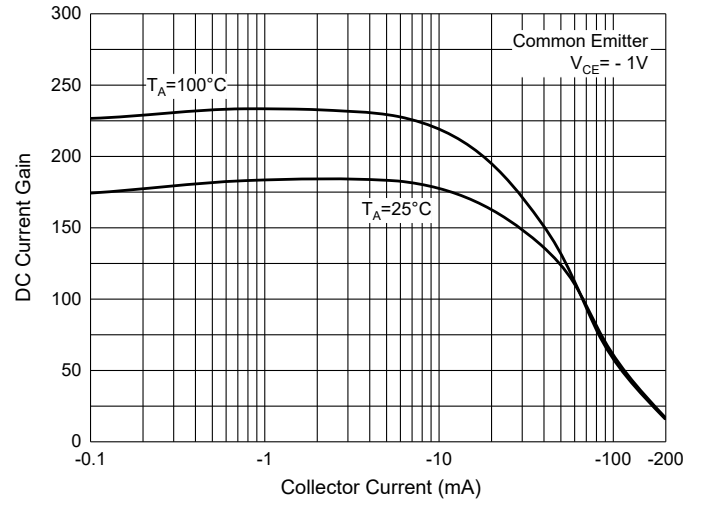


Fig. 9 - Collector-Emitter Saturation Voltage Characteristics

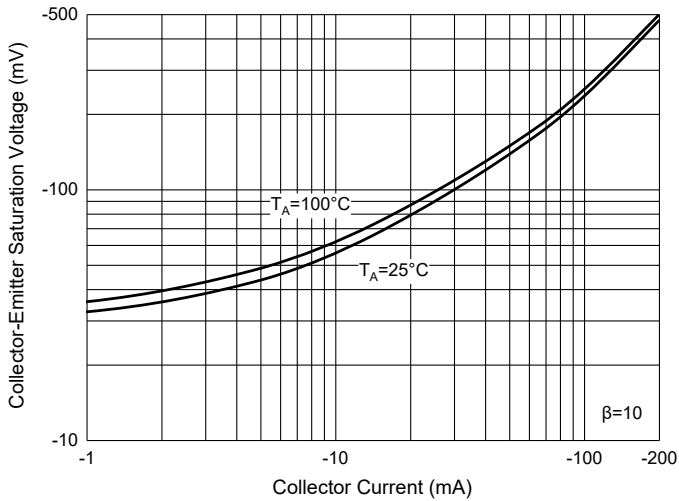


Fig. 10 - Base-Emitter Saturation Voltage Characteristics

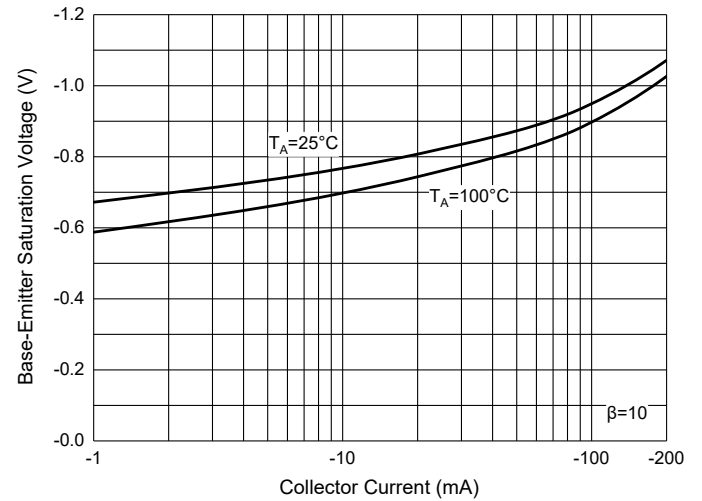


Fig. 11 - Base-Emitter Voltage Characteristics

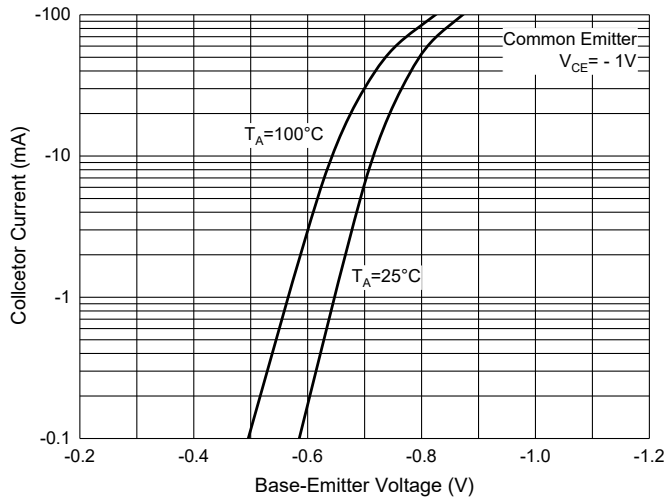
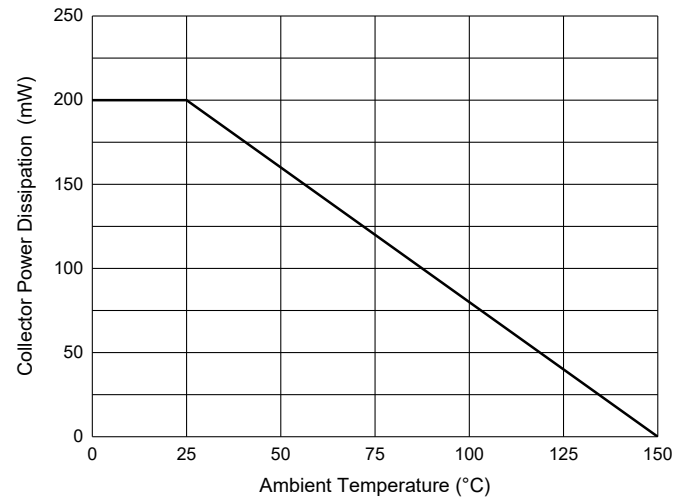


Fig. 12 - Collector Power Derating Curve



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

*****IMPORTANT NOTICE*****

Micro Commercial Components Corp. reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. *Micro Commercial Components Corp.* does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold *Micro Commercial Components Corp.* and all the companies whose products are represented on our website, harmless against all damages. *Micro Commercial Components Corp.* products are sold subject to the general terms and conditions of commercial sale, as published at <https://www.mccsemi.com/Home/TermsAndConditions>.

*****LIFE SUPPORT*****

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

*****CUSTOMER AWARENESS*****

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. **MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources.** MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - BJT category](#):

Click to view products by [Micro Commercial Components \(MCC\) manufacturer](#):

Other Similar products are found below :

[BC559C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [NJVMJD148T4G](#) [NTE16](#) [NTE195A](#) [IMX9T110](#) [2N4401-A](#) [2N4403](#) [2N6728](#)
[2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [FMC5AT148](#) [2N2369ADCSM](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC4618TLN](#) [CPH6501-](#)
[TL-E](#) [MCH4021-TL-E](#) [Jantx2N5416](#) [US6T6TR](#) [BAX18/A52R](#) [BC556/112](#) [IMZ2AT108](#) [MMST8098T146](#) [UMX21NTR](#) [MCH6102-TL-E](#)
[TTA1452B,S4X\(S](#) [2N3879](#) [NTE13](#) [NTE282](#) [NTE323](#) [NTE350](#) [NTE81](#) [JANTX2N2920L](#) [JANTX2N3735](#) [JANSR2N2222AUB](#)
[CMLT3946EG TR](#) [SNSS40600CF8T1G](#) [CMLT3906EG TR](#) [GRP-DATA-JANS2N2907AUB](#) [GRP-DATA-JANS2N2222AUA](#)
[MMDT3946FL3-7](#) [2N4240](#) [JANS2N3019](#) [MSB30KH-13](#) [2N2221AUB](#)